



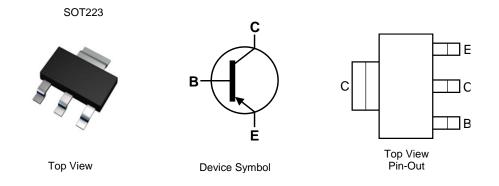
#### 300V PNP HIGH VOLTAGE TRANSISTOR IN SOT223

#### **Features**

- BV<sub>CEO</sub> > -300V
- I<sub>C</sub> = -0.5A Continuous Current
- I<sub>CM</sub> = -1A Peak Pulse Current
- Complementary NPN Type: FZT657
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

### **Mechanical Data**

- Package: SOT223
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208<sup>(3)</sup>
- Weight: 0.112 grams (Approximate)



### Ordering Information (Note 4)

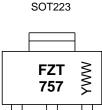
Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FZT757TA	Standard	FZT757	7	12	1,000

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4.For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



FZT 757 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 2 = 2022) WW or  $\overline{WW}$  = Week Code (01~53)



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-300	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-300	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-0.5	A
Peak Pulse Current	I <sub>СМ</sub>	-1	A

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.0		
Rower Dissipation	(Note 6)		2.0	w	
Power Dissipation	(Note 7)	PD	1.6	vv	
	(Note 8)		1.2		
	(Note 5)		41.7		
Thermal Resistance, Junction to Ambient	(Note 6)		62.5	°C/W	
mermai Resistance, Junction to Amplent	(Note 7)	R <sub>0JA</sub>	78.1	C/VV	
	(Note 8)		104		
Thermal Resistance, Junction to Leads	(Note 9)	R <sub>0JL</sub>	12.9	°C/W	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C		

#### ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.

7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.

8. Same as Note 5, except the device is mounted on minimum recommended pad layout.

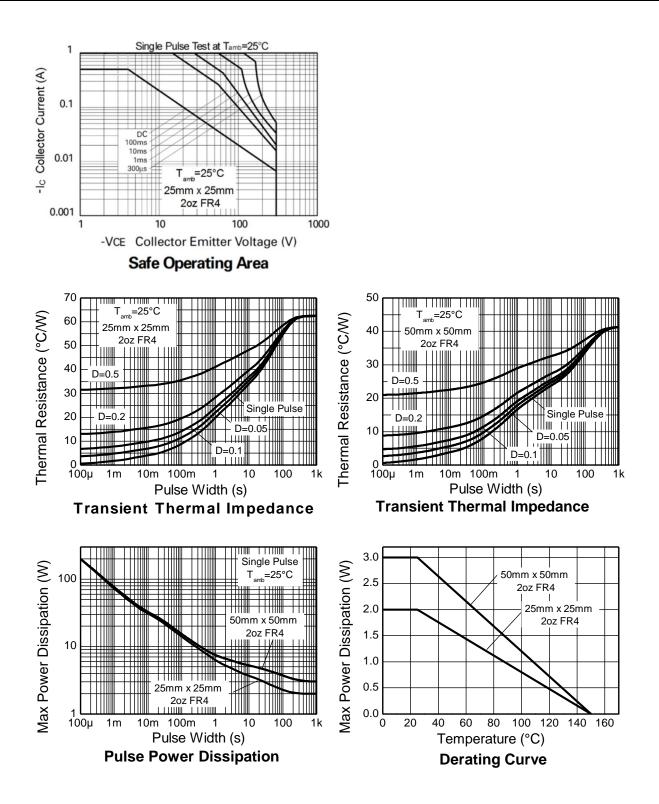
9. Thermal resistance from junction to solder-point (at the end of the collector lead).

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



**FZT757** 

# Thermal Characteristics and Derating Information





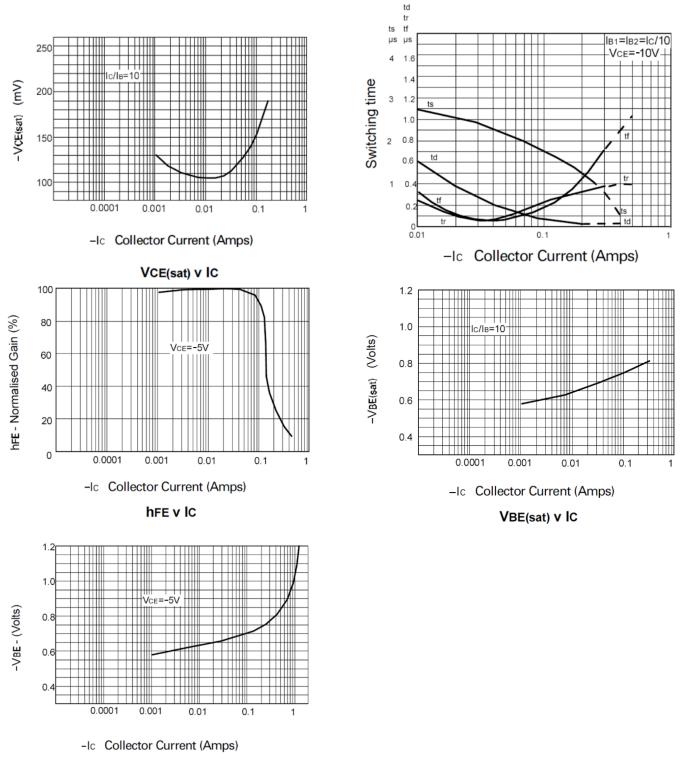
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-300	_	-	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	-300	-	-	V	$I_{C} = -10 \text{mA}$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-	-	V	I <sub>E</sub> = -100μA
Collector Cut-Off Current	I <sub>CBO</sub>	-	-1	-100	nA	V <sub>CB</sub> = -200V
Emitter Cut-Off Current	I <sub>EBO</sub>	_	-1	-20	nA	V <sub>EB</sub> = -5.6V
Collector-Emitter Saturation Voltage (Note 11)	V <sub>CE(sat)</sub>	-	-	-0.5	V	$I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -10 {\rm mA}$
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(sat)</sub>	-	_	-1.0	V	$I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -10 {\rm mA}$
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(on)</sub>	-	-	-1.0	V	$I_{C} = -100 \text{mA}, V_{CE} = -5 \text{V}$
DC Current Coin (Note 11)	hFE	40	-	-		$I_{C} = -10 \text{mA}, V_{CE} = -5 \text{V}$
DC Current Gain (Note 11)		50	-	-	_	$I_{C} = -100 \text{mA}, V_{CE} = -5 \text{V}$
Current Gain-Bandwidth Product	f <sub>T</sub>	30	-	-	MHz	$I_{C} = -10 \text{mA}, V_{CE} = -20 \text{V},$ f = 20MHz
Output Capacitance	Cobo	_	_	20	pF	$V_{CB} = -20V, f = 1MHz$

Note: 11. Measured under pulsed conditions. Pulse width  $\leq$  300 µs. Duty cycle  $\leq$  2%.



## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



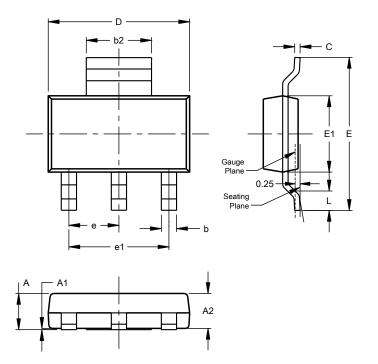
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# **Package Outline Dimensions**

Please see https://www.diodes.com/design/support/packaging/ for the latest version.

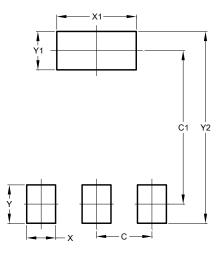


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SOT223 (Type DN)						
Dim	Min	Max	Тур			
Α		1.70				
A1	0.01	0.15				
A2	1.50	1.68	1.60			
b	0.60	0.80	0.70			
b2	2.90	3.10				
С	0.20	0.32				
D	6.30	6.70				
E	6.70	7.30				
E1	3.30	3.70				
е			2.30			
e1			4.60			
L	0.85					
All C	All Dimensions in mm					

# **Suggested Pad Layout**

Please see https://www.diodes.com/design/support/packaging/ for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)		
С	2.30		
C1	6.40		
Х	1.20		
X1	3.30		
Y	1.60		
Y1	1.60		
Y2	8.00		



**FZT757** 

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